

Description

Available in high power packages, the ITO-3P and TO-3P package.

Features

- I_{GT max.} = 50 mA
- Low thermal resistance with clip bonding
- Max. blocking voltage = V_{DRM}, V_{RRM} = 800V



- General purpose AC switch control
- Control loads in Motor, Fan, and Pump.
- Solenoid drivers
- LED Dimming
- Inrush current limiting circuits

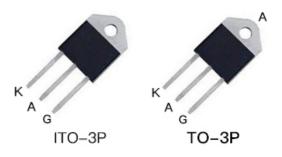
Absolute Maximum Ratings (T_A=25℃)

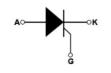
Rating		Symbol	Value
Peak repetitive off-state voltage (50Hz to 60Hz; Gate open) (Note 1)		V _{drm} V _{rrm}	800V
On-state RMS current (180° sine wave)		I _{T(RMS)}	55A
Non repetitive surge peak on-state current (full cycle, T initial = 25℃)	F=50Hz, t=10ms	I _{TSM}	300A
I ² t Value for fusing	t _P =10ms	l ² t	1800A ² s
Critical rate of rise of on-state current $I_G=2I_{GT}$	F=120Hz, TJ=125℃	di/dt	200A/µs
Non repetitive surge peak off-state voltage	t _P =10ms, TJ=25℃	V _{DSM} /V _{RSM}	V _{DRM} /V _{RRM} +100V
Peak gate current	t _P =20µs, T _J =125℃	I _{GM}	8A
Average gate power dissipation	TJ=125℃	P _{G(AV)}	1W
Storage junction temperature range		T _{STG}	-40℃ to +150℃
Operating junction temperature range		TJ	-40 ℃ to +125℃

Note:

1. $V_{\mbox{\tiny DRM}}$ and $V_{\mbox{\tiny RRM}}$ for all types can be applied on a continuous basis.

Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.







Electrical Characteristics (TJ=25°C, unless otherwise specified)

Parameter	Symbol	Value
V _D =12V, R _L =33Ω	I _{GT}	10mA~50mA
V _D =V _{DRM} , R _L =100Ω, T _J =125°C	V _{GD} Min.	0.2V
I _T =500mA	I _{Н Мах.} ⁽¹⁾	100mA
I _G =1.2I _{GT}	I _{L Max.}	125mA
V _D =67%V _{DRM} gate open, T _J =125℃	dv/dt _{Min.} ⁽¹⁾	1500V/µs

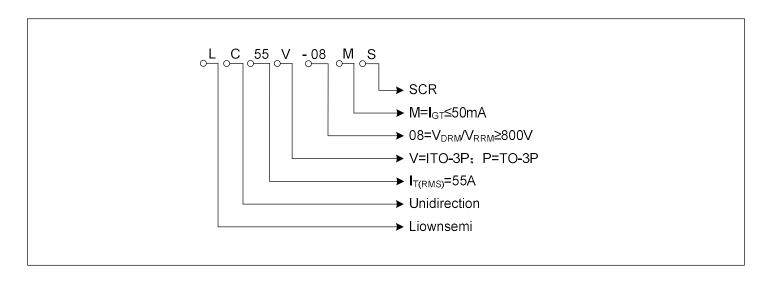
1. for both polarities of A2 referenced to A1

Static Characteristics

Test conditions	Symbol	Value
I _{TM} =55A, t _P =380µs, T _J =25℃	V _{T Max.} ⁽¹⁾	1.6V
Threshold voltage, TJ=125℃	V _{t0 Max.} ⁽¹⁾	0.85V
Dynamic resistance, TJ=125℃	R _{D Max.} ⁽¹⁾	8mΩ
V _{DRM} =V _{RRM} , Тј=25℃	IDRM Max.	5μΑ
V _{DRM} =V _{RRM} , T _J =125℃	IRRM Max.	8mA

1. for both polarities of A2 referenced to A1

Part Number Code

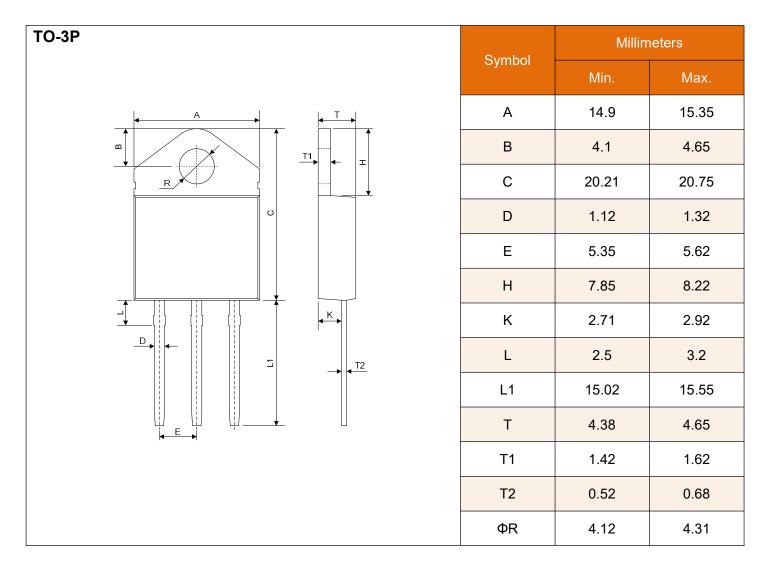




Ordering Information

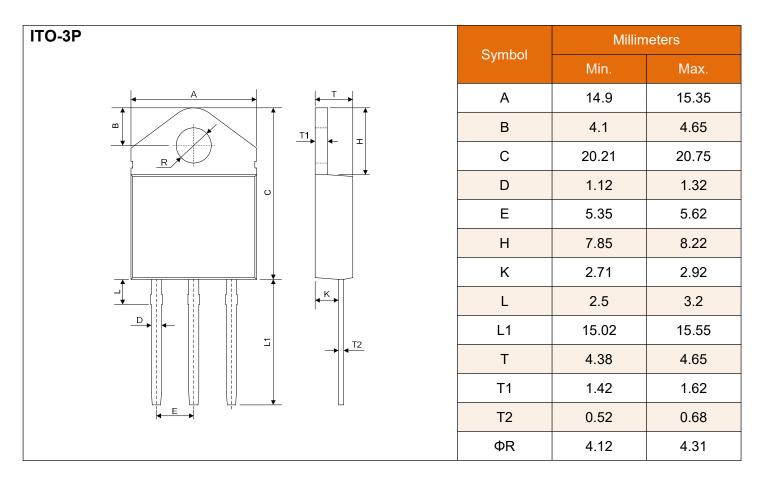
Part Number	Marking	Package
LC55P-08MS	LC55P-08MS	TO-3P
LC55V-08MS	LC55V-08MS	ITO-3P

Dimensions





Dimensions



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